

Powerex General Purpose Rectifier Diodes are designed with high blocking voltage capability and low forward voltage drop to minimize conduction losses. These are packaged in hermetic, ceramic Pow-R-Disc packages which can be mounted using commercially available clamps and heatsinks or fully assembled to a variety of air or water cooled heat exchangers.

FEATURES:

- Low On-State Voltage
- Hermetic Ceramic Package
- Excellent Surge and I^2t Ratings

APPLICATIONS:

- DC Power Supplies

ORDERING INFORMATION

Select the complete 12 digit Part Number using the table below.

EXAMPLE: R7S02215XXOO is a 2200V-1550A General Purpose Diode with a typical reverse recovery time of 25 μ s.

PART	Voltage Rating V_{DRM} - V_{RRM}	Voltage Code	Current Rating I_{tavg}	Current Code	Reverse Recovery t_{RR}	Lead Code
R7S0	2400	24	1550	15	XX	OO
	2200	22				
	2000	20			25 μ s typical	

Absolute Maximum Ratings

Characteristic	Symbol	Rating	Units
Repetitive Peak Reverse Voltage	V_{RRM}	2400	Volts
Average On-State Current, $T_C=90\text{ }^\circ\text{C}$	$I_{F(Avg.)}$	1550	A
RMS On-State Current, $T_C=90\text{ }^\circ\text{C}$	$I_{F(RMS)}$	2435	A
Average On-State Current, $T_C=55\text{ }^\circ\text{C}$	$I_{F(Avg.)}$	1830	A
RMS On-State Current, $T_C=55\text{ }^\circ\text{C}$	$I_{F(RMS)}$	2875	A
Peak 1 Cycle Surge Current [†] , 60Hz, $V_R=0.6*V_{RRM}$	I_{FSM}	8,162	A
Fuse Coordination I^2t , 60Hz	I^2t	2.78E+05	A^2s
Peak 1 Cycle Surge Current [†] , 60Hz, $V_R=0V$	I_{FSM}	10,600	A
Fuse Coordination I^2t , 50Hz	I^2t	4.68E+05	A^2s
Peak 3 Cycle Surge Current, 60Hz, $V_R=0V$	I_{FSM}	8,056	A
Peak 10 Cycle Surge Current, 60Hz, $V_R=0V$	I_{FSM}	5,936	A
Operating Temperature	T_j	-40 to+200	$^\circ\text{C}$
Storage Temperature	$T_{Stg.}$	-50 to+200	$^\circ\text{C}$
Approximate Weight		0.25	lb
		0.11	Kg
Mounting Force		2000-2400	lbs
		8.9 - 10.6	Knewtons

[†] Per NEMA Std. RS-282

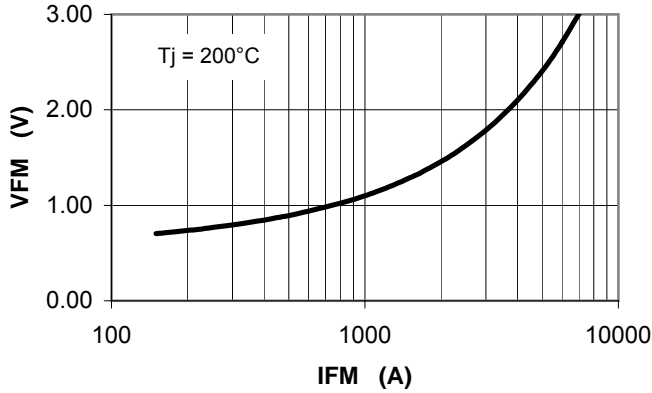
Electrical Characteristics, T_j=25°C unless otherwise specified

Characteristic	Symbol	Test Conditions	Rating			Units
			min	typ	max	
Repetitive Peak Reverse Leakage Current	I _{RRM}	T _j =200°C, V _{RRM} =Rated			150	ma
Peak On-State Voltage	V _{FM}	T _j =25°C, I _{FM} =1500A			1.35	V
V _{FM} Model, Low Level	V ₀	T _j =200°C			0.754	V
V _{FM} = V ₀ + r•I _{FM}	r	15% I _{FM} - π•I _{FM}			0.336	mΩ
V _{FM} Model, High Level	V ₀	T _j =200°C			0.946	V
V _{FM} = V ₀ + r•I _{FM}	r	π•I _{FM} - I _{FSM}			0.292	mΩ
V _{FM} Model, 4-Term	A	T _j =200°C			0.449	
V _{FM} = A + B•Ln(I _{FM}) +	B	15% I _{FM} - I _{FSM}			0.0256	
C•(I _{FM}) + D•(I _{FM}) ^{1/2}	C				2.454E-04	
	D				0.00726	
Reverse Recovery Time	t _{RR}	T _j =25°C, I _{FM} =1500A di _R /dt = 25 A/μs		25		μs

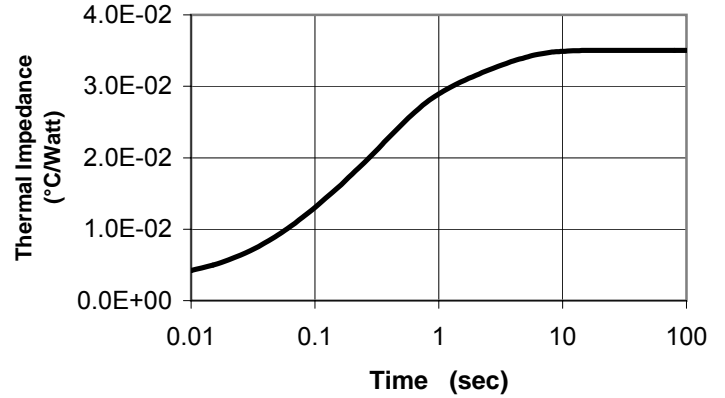
Thermal Characteristics

Characteristic	Symbol	Test Conditions	Rating			Units	
			min	typ	max		
Thermal Resistance							
Junction to Case	Rθ _{jc}	Double side cooled		0.03	0.035	°C/Watt	
Case to Sink	Rθ _{cs}	Double side cooled		0.018	0.02	°C/Watt	
Thermal Impedance Model	Zθ _{jc}	Double side cooled					
Zθ _{jc} (t) = Σ(A(N)•(1-exp(-t/Tau(N))))		where:	N =	1	2	3	4
			A(N) =	2.54E-03	6.39E-03	1.82E-02	7.91E-03
			Tau(N) =	7.99E-04	5.29E-02	3.30E-01	2.39E+00

Maximum On-State Voltage Drop

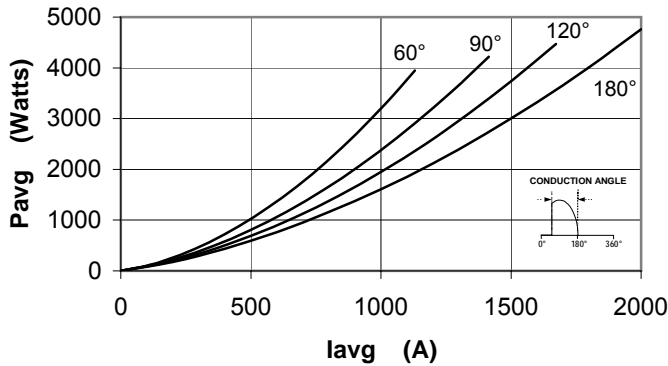


MAXIMUM TRANSIENT THERMAL IMPEDANCE



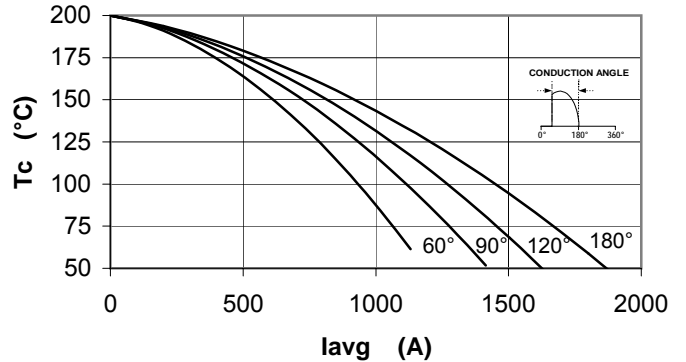
Maximum On-State Power Dissipation

Sinusoidal



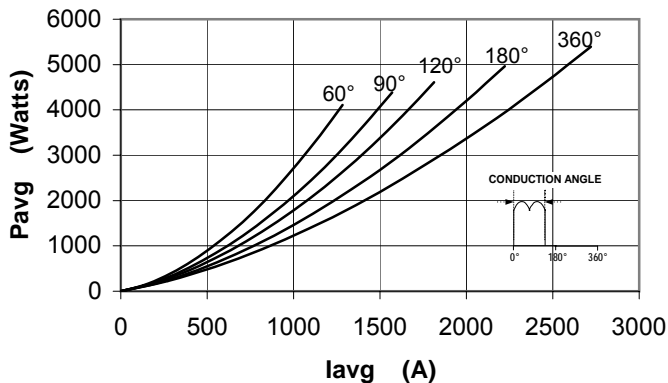
Maximum Allowable Case Temperature

Sinusoidal Waveform



Maximum On-State Power Dissipation

Square Waveform



Maximum Allowable Case Temperature

Square Waveform

